# AN78Lxx/AN78LxxM Series

3-pin positive output voltage regulator (100 mA type)

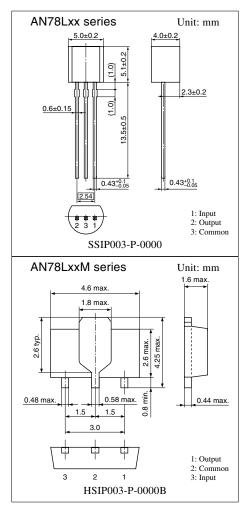
## Overview

The AN78Lxx series and the AN78LxxM series are 3pin fixed positive output type monolithic voltage regulator.

A stabilized fixed output voltage is obtained from an unstable DC input voltage without using any external parts. 12 types of fixed output voltage are available; 4V, 5V, 6V, 7V, 8V, 9V, 10V, 12V, 15V, 18V, 20V and 24V. They can be used widely as power circuits with a current capacity of up to 100mA.

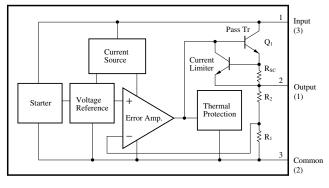
#### Features

- No external components
- Output voltage: 4V, 5V, 6V, 7V, 8V, 9V, 10V, 12V, 15V, 18V, 20V, 24V
- Built-in overcurrent limit circuit
- Built-in thermal overload protection circuit



Note) The packages (SSIP003-P-0000 and HSIP003-P-0000B) of this product will be changed to lead-free type (SSIP003-P-0000S and HSIP003-P-0000Q). See the new package dimensions section later of this datasheet.

#### ■ Block Diagram (AN78Lxx series)



Note) The number in ( ) shows the pin number for the AN78LxxM series.

#### Absolute Maximum Ratings at $T_a = 25^{\circ}C$

Parameter		Symbol	Rating	Unit
Input voltage		N	35 *1	v
		VI	40 *2	V
Power dissipation		PD	650 *3	mW
Operating ambient ten	nperature	T <sub>opr</sub>	-30 to +80	°C
<u>C</u> ttt	AN78Lxx series	т	-55 to +150	00
Storage temperature	AN78LxxM series	T <sub>stg</sub>	-55 to +125	°C

\*1 AN78L04/M, AN78L05/M, AN78L06/M, AN78L07/M, AN78L08/M, AN78L09/M, AN78L10/M, AN78L12/M, AN78L15/M

\*2 AN78L18/M, AN78L20/M, AN78L24/M

\*3 Follow the derating curve. When T<sub>1</sub> exceeds 150°C, the internal circuit cuts off the output.

AN78LxxM series is mounted on a standard board (glass epoxy: 20mm  $\times 20$ mm  $\times t1.7$ mm with Cu foil of 1cm<sup>2</sup> or more).

#### Electrical Characteristics at $T_a = 25^{\circ}C$

#### • AN78L04, AN78L04M (4V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	3.84	4	4.16	V
Output voltage tolerance	Vo	$V_{I} = 6.5$ to 19V, $I_{O} = 1$ to 70mA	3.8		4.2	V
Line regulation	REGIN	$V_I = 6.5$ to 19V, $T_j = 25^{\circ}C$		50	145	mV
Line regulation	KEUIN	$V_{I} = 7$ to 19V, $T_{j} = 25^{\circ}C$		40	95	mV
Lood regulation	REG <sub>L</sub> ⊢	$I_0 = 1$ to 100mA, $T_j = 25^{\circ}C$		10	55	mV
Load regulation		$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		4.5	30	mV
Bias current	I <sub>Bias</sub>	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_{I} = 7$ to 19V, $T_{j} = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		—	0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to $100kHz$		40		μV
Ripple rejection ratio	RR	$V_I = 7$ to 17V, $I_O = 40$ mA, $f = 120$ Hz	48	58		dB
Minimum input/output voltage difference	V <sub>DIF(min)</sub>	$T_j = 25^{\circ}C$		1.7		v
Output short-circuit current	I <sub>O(Short)</sub>	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_0/T_a$	$I_0 = 5mA, T_j = 0$ to $125^{\circ}C$		- 0.6		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_I = 9V$ ,  $I_0 = 40$ mA,  $C_I = 0.33\mu$ F,  $C_0 = 0.1\mu$ F,  $T_j = 0$  to 125°C (AN78L04) and  $T_j = 0$  to 100°C (AN78L04M)

## ■ Electrical Characteristics at T<sub>a</sub> = 25°C (continued)

## • AN78L05, AN78L05M (5V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	4.8	5	5.2	V
Output voltage tolerance	Vo	$V_{I}$ = 7.5 to 20V, $I_{O}$ = 1 to 70mA	4.75		5.25	V
Line regulation	DEC	$V_I = 7.5$ to 20V, $T_j = 25^{\circ}C$		55	150	mV
Line regulation	REGIN	$V_{I} = 8$ to 20V, $T_{j} = 25^{\circ}C$		45	100	mV
Load regulation	DEC	$I_0 = 1$ to 100mA, $T_j = 25^{\circ}C$		11	60	mV
Load regulation	REGL	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		5	30	mV
Bias current	I <sub>Bias</sub>	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_{I} = 8$ to 20V, $T_{j} = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$			0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to $100kHz$		40		μV
Ripple rejection ratio	RR	$V_I = 8$ to 18V, $I_O = 40$ mA, $f = 120$ Hz	47	57		dB
Minimum input/output voltage difference	V <sub>DIF(min)</sub>	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	I <sub>O(Short)</sub>	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_0/T_a$	$I_0 = 5mA, T_j = 0 \text{ to } 125^{\circ}C$		- 0.65		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_I = 10V$ ,  $\hat{I}_0 = 40$ mA,  $C_I = 0.33\mu$ F,  $C_0 = 0.1\mu$ F,  $T_j = 0$  to  $125^{\circ}$ C (AN78L05) and  $T_j = 0$  to  $100^{\circ}$ C (AN78L05M)

#### • AN78L06, AN78L06M (6V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	5.76	6	6.24	V
Output voltage tolerance	Vo	$V_{I} = 8.5$ to 21V, $I_{O} = 1$ to 70mA	5.7		6.3	V
Line regulation	REG <sub>IN</sub>	$V_{\rm I}$ = 8.5 to 21V, $T_{\rm j}$ = 25°C		60	155	mV
		$V_I = 9$ to 21V, $T_j = 25^{\circ}C$		50	105	mV
Load regulation	DEC	$I_0 = 1$ to 100mA, $T_j = 25^{\circ}C$		12	65	mV
Load regulation	REGL	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		5.5	35	mV
Bias current	I <sub>Bias</sub>	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 9$ to 21V, $T_j = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$			0.1	mA
Output noise voltage	$V_{no}$	f = 10Hz to $100kHz$		50		μV
Ripple rejection ratio	RR	$V_I = 9$ to 19V, $I_O = 40$ mA, $f = 120$ Hz	46	56		dB
Minimum input/output voltage difference	V <sub>DIF(min)</sub>	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	$I_{O(Short)}$	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_0/T_a$	$I_0 = 5mA, T_j = 0 \text{ to } 125^{\circ}C$		- 0.7		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_1 = 11V$ ,  $\hat{I}_0 = 40$ mA,  $C_1 = 0.33\mu$ F,  $C_0 = 0.1\mu$ F,  $T_j = 0$  to  $125^{\circ}$ C (AN78L06) and  $T_j = 0$  to  $100^{\circ}$ C (AN78L06M)

#### • AN78L07, AN78L07M (7V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	6.72	7	7.28	V
Output voltage tolerance	Vo	$V_{I} = 9.5$ to 22V, $I_{O} = 1$ to 70mA	6.65		7.35	V
Line regulation	REGIN	$V_I = 9.5$ to 22V, $T_j = 25^{\circ}C$		70	165	mV
Line regulation	KEOIN	$V_I = 10$ to 22V, $T_j = 25^{\circ}C$		60	115	mV
Load regulation	DEC	$I_0 = 1$ to 100mA, $T_j = 25^{\circ}C$		13	75	mV
Load regulation	REGL	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$	_	6	35	mV
Bias current	I <sub>Bias</sub>	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 10$ to 22V, $T_j = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$			0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to $100kHz$		50		μV
Ripple rejection ratio	RR	$V_{I} = 10$ to 20V, $I_{O} = 40$ mA, $f = 120$ Hz	45	55		dB
Minimum input/output voltage difference	V <sub>DIF(min)</sub>	$T_j = 25^{\circ}C$		1.7		v
Output short-circuit current	I <sub>O(Short)</sub>	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_0/T_a$	$I_0 = 5mA$ , $T_j = 0$ to $125^{\circ}C$		- 0.75		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_I = 12V$ ,  $\tilde{I}_0 = 40$ mA,  $C_I = 0.33\mu$ F,  $C_0 = 0.1\mu$ F,  $T_j = 0$  to  $125^{\circ}$ C (AN78L07) and  $T_j = 0$  to  $100^{\circ}$ C (AN78L07M)

#### • AN78L08, AN78L08M (8V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	7.7	8	8.3	V
Output voltage tolerance	Vo	$V_I = 10.5$ to 23V, $I_O = 1$ to 70mA	7.6	—	8.4	V
Line regulation	REGIN	$V_I = 10.5$ to 23V, $T_j = 25^{\circ}C$		80	175	mV
	KEOIN	$V_{I} = 11$ to 23V, $T_{j} = 25^{\circ}C$		70	125	mV
Load regulation	DEC	$I_0 = 1$ to 100mA, $T_j = 25^{\circ}C$		15	80	mV
Load regulation	REGL	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		7	40	mV
Bias current	I <sub>Bias</sub>	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_{I} = 11$ to 23V, $T_{j} = 25^{\circ}C$		—	1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$			0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to $100kHz$		60		μV
Ripple rejection ratio	RR	$V_{I} = 11$ to 21V, $I_{O} = 40$ mA, $f = 120$ Hz	44	54		dB
Minimum input/output voltage difference	V <sub>DIF(min)</sub>	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	I <sub>O(Short)</sub>	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_0/T_a$	$I_0 = 5mA, T_j = 0 \text{ to } 125^{\circ}C$		- 0.8		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_I = 14V$ ,  $I_O = 40$ mA,  $C_I = 0.33\mu$ F,  $C_O = 0.1\mu$ F,  $T_j = 0$  to  $125^{\circ}$ C (AN78L08) and  $T_j = 0$  to  $100^{\circ}$ C (AN78L08M)

## • AN78L09, AN78L09M (9V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	8.64	9	9.35	V
Output voltage tolerance	Vo	$V_{I} = 11.5$ to 24V, $I_{O} = 1$ to 70mA	8.55		9.45	V
Line regulation	REGIN	$V_{I}{=}11.5$ to 24V, $T_{j}{=}25^{\circ}C$		90	190	mV
Line regulation	KEGIN	$V_I = 12 \text{ to } 24V, T_j = 25^{\circ}C$		80	140	mV
Load regulation	DEC	$I_0 = 1$ to 100mA, $T_j = 25^{\circ}C$		16	85	mV
Load regulation	REGL	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		8	45	mV
Bias current	I <sub>Bias</sub>	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_{I} = 12 \text{ to } 24V, T_{j} = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$			0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to $100kHz$		65		μV
Ripple rejection ratio	RR	$V_I = 12$ to 22V, $I_O = 40$ mA, $f = 120$ Hz	43	53		dB
Minimum input/output voltage difference	V <sub>DIF(min)</sub>	$T_j = 25^{\circ}C$		1.7		v
Output short-circuit current	$I_{O(Short)}$	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_0/T_a$	$I_0 = 5mA, T_j = 0 \text{ to } 125^{\circ}C$		- 0.85		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_I = 15V$ ,  $\tilde{I}_0 = 40$ mA,  $C_I = 0.33\mu$ F,  $C_0 = 0.1\mu$ F,  $T_j = 0$  to  $125^{\circ}$ C (AN78L09) and  $T_j = 0$  to  $100^{\circ}$ C (AN78L09M)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	9.6	10	10.4	V
Output voltage tolerance	Vo	$V_{\rm I}{=}12.5$ to 25V, $I_{\rm O}{=}1$ to 70mA	9.5		10.5	V
Line regulation	REGIN	$V_I = 12.5$ to 25V, $T_j = 25^{\circ}C$		100	210	mV
Line regulation	KEOIN	$V_I = 13$ to 25V, $T_j = 25^{\circ}C$		90	160	mV
Load regulation	REG	$I_0 = 1$ to 100mA, $T_j = 25^{\circ}C$		17	90	mV
Load regulation	KEGL	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		9	45	mV
Bias current	I <sub>Bias</sub>	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 13$ to 25V, $T_j = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$			0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to $100kHz$		70		μν
Ripple rejection ratio	RR	$V_I = 13$ to 23V, $I_O = 40$ mA, $f = 120$ Hz	42	52		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	I <sub>O(Short)</sub>	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_0/T_a$	$I_0 = 5mA, T_j = 0$ to $125^{\circ}C$	_	- 0.9		mV/°C

#### AN78L10, AN78L10M (10V type)

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_I = 16V$ ,  $I_0 = 40$ mA,  $C_1 = 0.33\mu$ F,  $C_0 = 0.1\mu$ F,  $T_j = 0$  to  $125^{\circ}$ C (AN78L10) and  $T_j = 0$  to  $100^{\circ}$ C (AN78L10M)

## • AN78L12, AN78L12M (12V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	11.5	12	12.5	v
Output voltage tolerance	Vo	$V_I = 14.5$ to 27V, $I_O = 1$ to 70mA	11.4	—	12.6	V
Line regulation	REGIN	$V_I = 14.5$ to 27V, $T_j = 25^{\circ}C$		120	250	mV
Line regulation	KEGIN	$V_{I} = 15$ to 27V, $T_{j} = 25^{\circ}C$		100	200	mV
Load regulation	DEC	$I_0 = 1$ to 100mA, $T_j = 25^{\circ}C$		20	100	mV
Load regulation	REGL	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		10	50	mV
Bias current	I <sub>Bias</sub>	$T_j = 25^{\circ}C$		2	3.5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_{I} = 15$ to 27V, $T_{j} = 25^{\circ}C$		_	1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		—	0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to $100kHz$		80		μν
Ripple rejection ratio	RR	$V_I = 15$ to 25V, $I_O = 40$ mA, $f = 120$ Hz	40	50		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	$I_{O(Short)}$	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_0/T_a$	$I_0 = 5mA, T_j = 0 \text{ to } 125^{\circ}C$		-1		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_I = 19V$ ,  $\tilde{I}_0 = 40$ mA,  $C_I = 0.33\mu$ F,  $C_0 = 0.1\mu$ F,  $T_j = 0$  to  $125^{\circ}$ C (AN78L12) and  $T_j = 0$  to  $100^{\circ}$ C (AN78L12M)

Parameter	Symbol	Conditions	Min	Тур	Мах	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	14.4	15	15.6	V
Output voltage tolerance	Vo	$V_{I} = 17.5$ to 30V, $I_{O} = 1$ to 70mA	14.25		15.75	V
Line regulation	REGIN	$V_I = 17.5$ to 30V, $T_j = 25^{\circ}C$		130	300	mV
Line regulation	KLOIN	$V_I = 18$ to 30V, $T_j = 25^{\circ}C$		110	250	mV
Load regulation	REG	$I_0 = 1$ to 100mA, $T_j = 25^{\circ}C$		25	150	mV
Load regulation	KEGL	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		12	75	mV
Bias current	I <sub>Bias</sub>	$T_j = 25^{\circ}C$		2	3.5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 18$ to 30V, $T_j = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$			0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to $100kHz$		90		μV
Ripple rejection ratio	RR	$V_{I} = 18$ to 28V, $I_{O} = 40$ mA, $f = 120$ Hz	38	48		dB
Minimum input/output voltage difference	V <sub>DIF(min)</sub>	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	I <sub>O(Short)</sub>	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_0/T_a$	$I_0 = 5mA, T_j = 0$ to $125^{\circ}C$		-1.3		mV/°C

#### AN78L15, AN78L15M (15V type)

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_1 = 23V$ ,  $I_0 = 40$ mA,  $C_1 = 0.33\mu$ F,  $C_0 = 0.1\mu$ F,  $T_j = 0$  to  $125^{\circ}$ C (AN78L15) and  $T_j = 0$  to  $100^{\circ}$ C (AN78L15M)

## ■ Electrical Characteristics at T<sub>a</sub> = 25°C (continued)

## • AN78L18, AN78L18M (18V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	17.3	18	18.7	V
Output voltage tolerance	Vo	$V_{I} = 20.5$ to 33V, $I_{O} = 1$ to 70mA	17.1		18.9	v
Line regulation	REGIN	$V_{I} = 20.5$ to 33V, $T_{j} = 25^{\circ}C$		45	300	mV
Line regulation	KEUIN	$V_{I} = 21$ to 33V, $T_{j} = 25^{\circ}C$		35	250	mV
Load regulation	DEC	$I_0 = 1$ to 100mA, $T_j = 25^{\circ}C$		30	170	mV
	REGL	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		15	85	mV
Bias current	I <sub>Bias</sub>	$T_j = 25^{\circ}C$		2	3.5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_{I} = 21$ to 33V, $T_{j} = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$			0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to $100kHz$		150		μV
Ripple rejection ratio	RR	$V_I = 21$ to 31V, $I_O = 40$ mA, $f = 120$ Hz	36	46		dB
Minimum input/output voltage difference	V <sub>DIF(min)</sub>	$T_j = 25^{\circ}C$		1.7		v
Output short-circuit current	I <sub>O(Short)</sub>	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_0/T_a$	$I_0 = 5mA$ , $T_j = 0$ to $125^{\circ}C$		-1.5		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_I = 27V$ ,  $\tilde{I}_0 = 40$ mA,  $C_I = 0.33\mu$ F,  $C_0 = 0.1\mu$ F,  $T_j = 0$  to  $125^{\circ}$ C (AN78L18) and  $T_j = 0$  to  $100^{\circ}$ C (AN78L18M)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	19.2	20	20.8	V
Output voltage tolerance	Vo	$V_{I} = 22.5$ to 35V, $I_{O} = 1$ to 70mA	19		21	V
Line regulation	REGIN	$V_I = 22.5$ to 35V, $T_j = 25^{\circ}C$		50	300	mV
	KLO <sub>IN</sub>	$V_{\rm I}{=}23$ to 35V, $T_{\rm j}{=}25^\circ C$		40	250	mV
Load regulation	DEC	$I_0 = 1$ to 100mA, $T_j = 25^{\circ}C$		35	180	mV
Load regulation	REGL	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		17	90	mV
Bias current	I <sub>Bias</sub>	$T_j = 25^{\circ}C$		2	3.5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 23$ to 35V, $T_j = 25^{\circ}C$		—	1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		_	0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to $100kHz$		170	—	μV
Ripple rejection ratio	RR	$V_I = 23$ to 33V, $I_O = 40$ mA, $f = 120$ Hz	34	44		dB
Minimum input/output voltage difference	V <sub>DIF(min)</sub>	$T_j = 25^{\circ}C$		1.7		v
Output short-circuit current	I <sub>O(Short)</sub>	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_0/T_a$	$I_0 = 5mA, T_j = 0$ to $125^{\circ}C$		-1.7		mV/°C

#### AN78L20, AN78L20M (20V type)

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified,  $V_1 = 29V$ ,  $\tilde{I}_0 = 40$ mA,  $C_1 = 0.33\mu$ F,  $C_0 = 0.1\mu$ F,  $T_j = 0$  to  $125^{\circ}$ C (AN78L20) and  $T_j = 0$  to  $100^{\circ}$ C (AN78L20M)

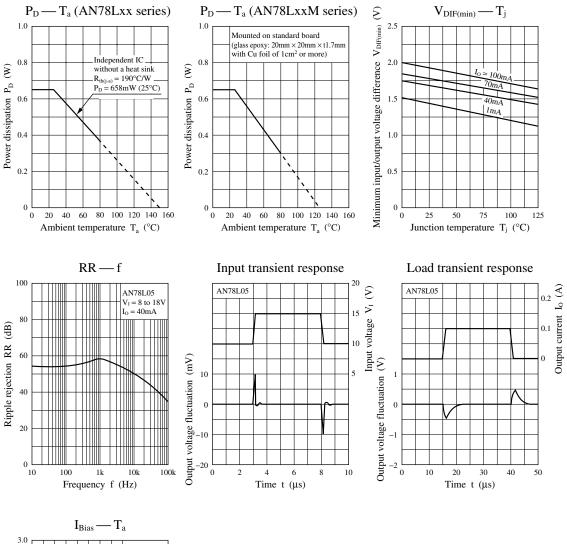
## • AN78L24, AN78L24M (24V type)

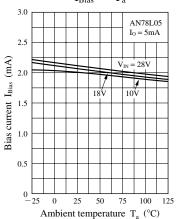
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	23	24	25	v
Output voltage tolerance	Vo	$V_{I} = 26.5$ to 39V, $I_{O} = 1$ to 70mA	22.8		25.2	v
Line regulation	REGIN	$V_1 = 26.5$ to 39V, $T_j = 25^{\circ}C$		60	300	mV
		$V_{I} = 27$ to 39V, $T_{j} = 25^{\circ}C$		50	250	mV
Load regulation	REGL	$I_0 = 1$ to 100mA, $T_j = 25^{\circ}C$		40	200	mV
		$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$		20	100	mV
Bias current	I <sub>Bias</sub>	$T_j = 25^{\circ}C$		2	3.5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 27$ to 39V, $T_j = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1$ to 40mA, $T_j = 25^{\circ}C$			0.1	mA
Output noise voltage	V <sub>no</sub>	f = 10Hz to $100kHz$		200		μV
Ripple rejection ratio	RR	$V_I = 27$ to 37V, $I_O = 40$ mA, $f = 120$ Hz	34	44		dB
Minimum input/output voltage difference	V <sub>DIF(min)</sub>	$T_j = 25^{\circ}C$		1.7		v
Output short-circuit current	I <sub>O(Short)</sub>	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_0/T_a$	$I_0 = 5$ mA, $T_j = 0$ to $125$ °C		-2		mV/°C

Note 1) The specified condition  $T_j = 25^{\circ}C$  means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

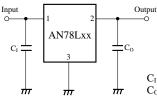
Note 2) Unless otherwise specified,  $V_1 = 33V$ ,  $\overline{I_0} = 40$ mA,  $C_1 = 0.33\mu$ F,  $C_0 = 0.1\mu$ F,  $T_j = 0$  to 125°C (AN78L24) and  $T_j = 0$  to 100°C (AN78L24M)

#### Main Characteristics





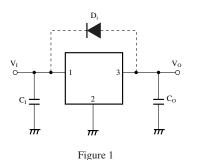
#### Basic Regulator Circuit



 $C_I$  is necessary when the input line is long.  $C_O$  improves the transient response.

Usage Notes

1. Cautions for a basic circuit



- $\begin{array}{l} C_{I}: \mbox{ When a wiring from a smoothing circuit to a three-pin regulator} \\ \mbox{ is long, it is likely to oscillate at output. A capacitor of 0.1 $\mu$F to 0.47 $\mu$F should be connected near an input pin. } \end{array}$
- $C_0$ : When any sudden change of load current is likely to occur, connect an electrolytic capacitor of  $10\mu$ F to  $100\mu$ F to improve a transitional response of output voltage.
- D<sub>i</sub>: Normally unnecessary. But add it in the case that there is a residual voltage at the output capacitor Co even after switching off the supply power because a current is likely to flow into an output pin of the IC and damage the IC.

## 2. Other caution items

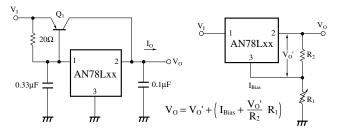
1) Short-circuit between the input pin and GND pin

If the input pin is short-circuitted to GND or is cut off when a large capacitance capacitor has been connected to the IC's load, a voltage of a capacitor connected to an output pin is applied between input/output of the IC and this likely results in damage of the IC. It is necessary, therefore, to connect a diode, as shown in figure 2, to counter the reverse bias between input/output pins. Гарие 2

#### 2) Floating of GND pin

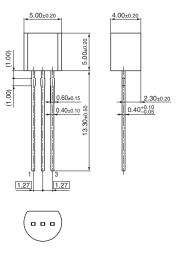
If a GND pin is made floating in an operating mode, an unstabilized input voltage is outputted. In this case, a thermal protection circuit inside the IC does not normally operate. In this state, if the load is short-circuited or overloaded, it is likely to damage the IC.

#### Application Circuit Examples

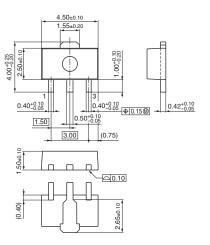


Note)  $V_{\rm O}$  varies due to sample to sample variation of  $I_{\rm Bias}$  . Never fail to adjust individually with  $R_1$  .

- New Package Dimensions (Unit: mm)
- SSIP003-P-0000S (Lead-free package)



• HSIP003-P-0000Q (Lead-free package)



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